



# THz Imaging Radar: Technology Development for Multi-pixel Multi-color Architectures

Imran Mehdi, Ken Cooper, Peter Siegel, Goutam Chattopadhyay, Cecile Jung, Jose Siles, and Theodore Reck

Jet Propulsion Laboratory, California Institute of Technology

*©2012 Copyright California Institute of Technology,  
Government sponsorship acknowledged*

WFC: Emerging Technology of THz Imaging Systems, Devices and Algorithms  
Friday, June 22

# Outline



- Motivation
- Imaging arrays
  - Methodology
  - Technology
  - Roadmap
- Conclusion

- Submillimeter-wave heterodyne receivers have a long and noteworthy history in exploring our universe (MLS, MIRO, HIFI)
- Recent work has also demonstrated the use of this technology for concealed weapons detection (Cooper et. al talk this conference)
- Most receivers deployed at these frequencies have been single pixel and fairly bulky systems
- Two important considerations require a paradigm shift in terms of how we build these receivers for the future
  - Large count arrays will require that each receiver is low-mass, low-power and extremely small.
  - A “batch level” technology is needed for manufacturing arrays.

# Submm Imaging Radar

Visible, IR

Microwaves, RF

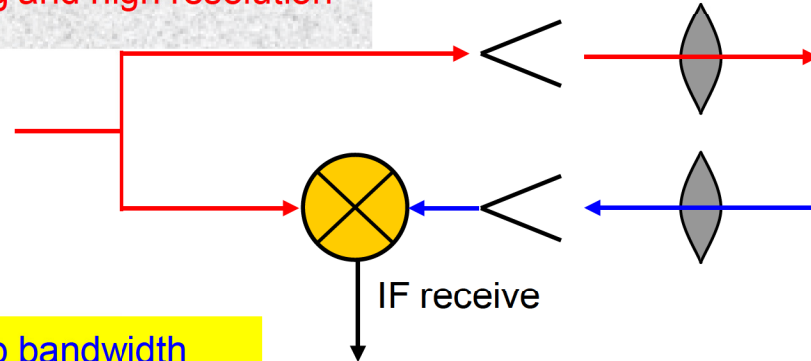
high resolution, but non-penetrating

THz Gap

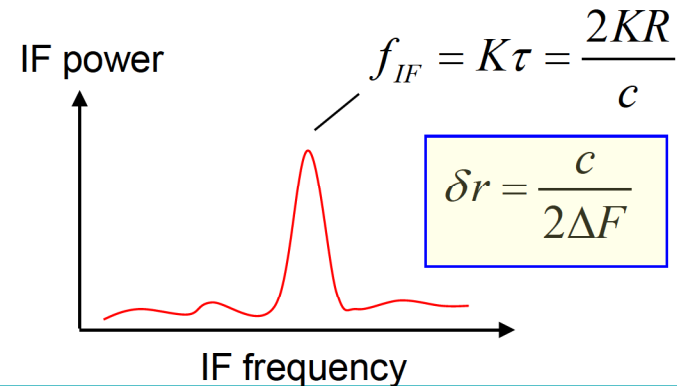
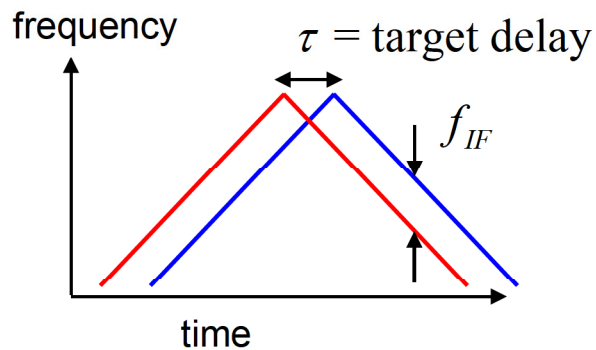
penetrating, but low resolution

penetrating and high resolution

$K = \text{chirp rate (Hz/s)}$

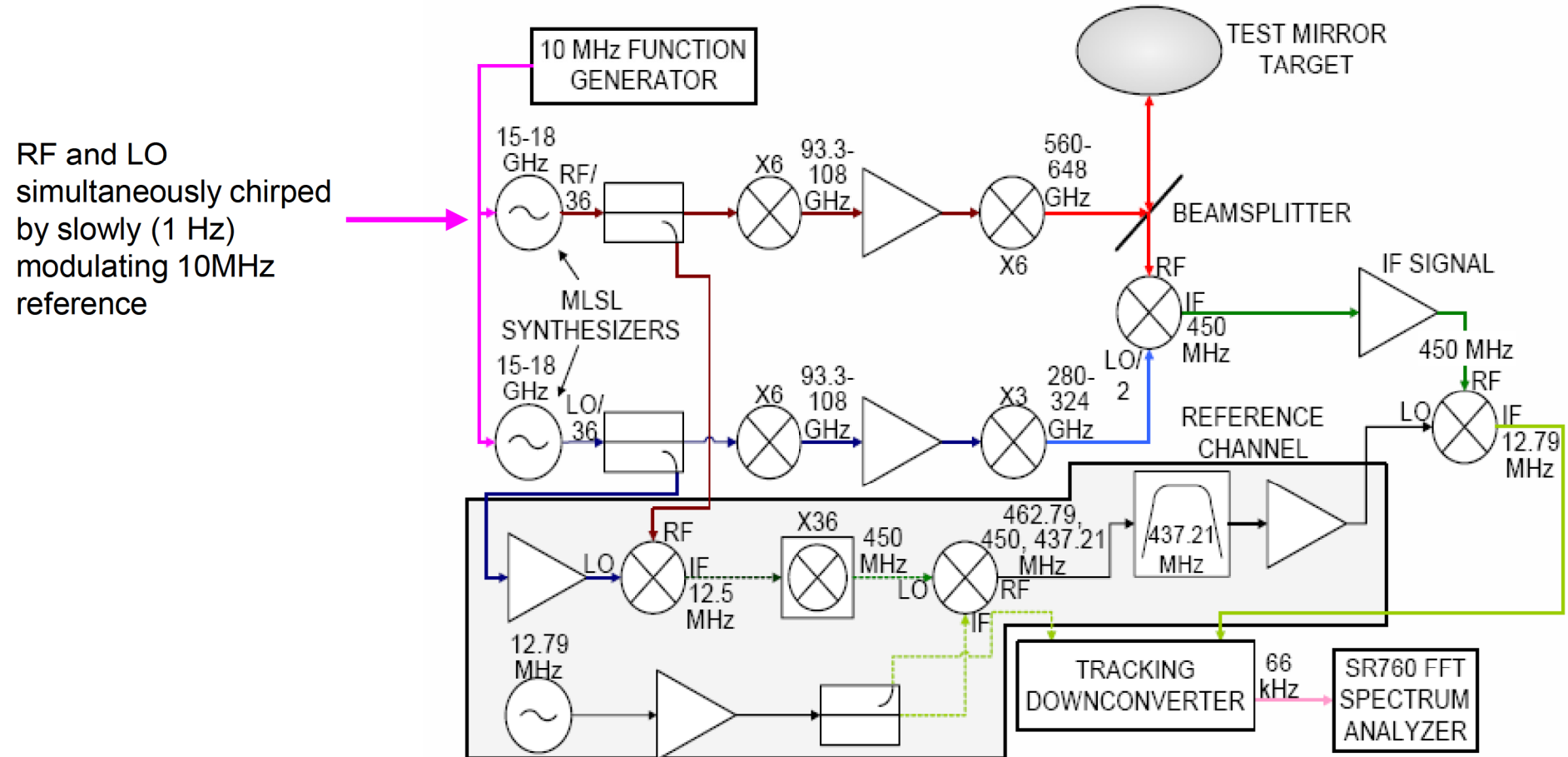


Range resolution: inversely proportional to chirp bandwidth





## Evolution to FMCW Radar



## First results, 2008

$$f_{IF} = f_0 + \frac{2KR}{c} = f_0 \pm 470 \text{ Hz}$$

630 GHz radar proof-of-principle achieved. First results:

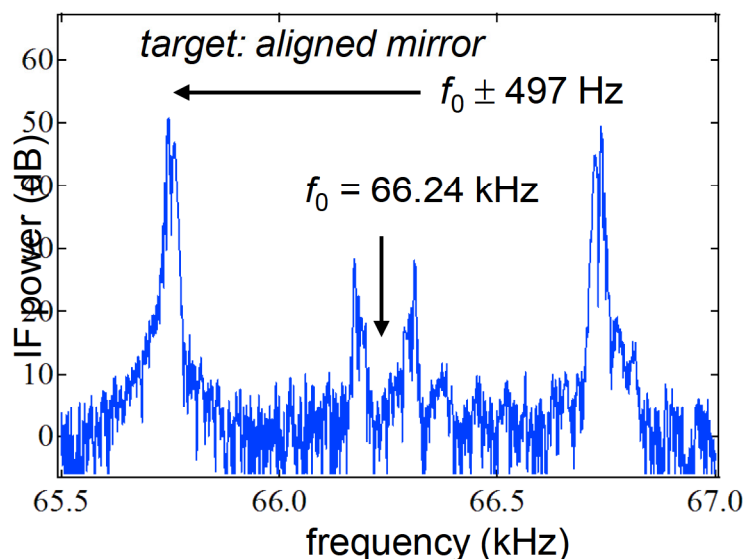
$$f_0 = 66.24 \text{ kHz}$$

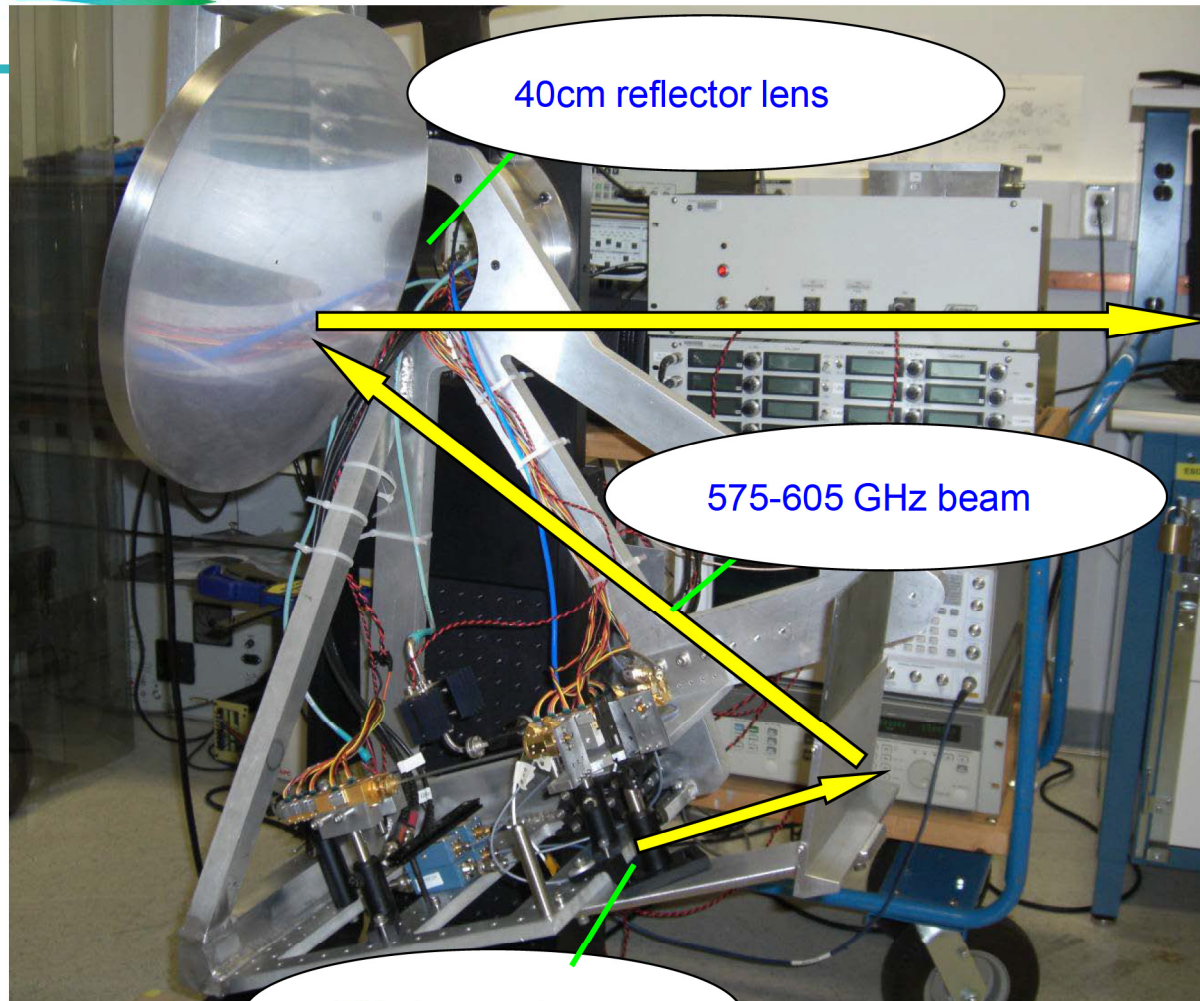
$$R = 4.4 \text{ m}$$

$$K = \pm \frac{8 \text{ GHz}}{0.5 \text{ s}}$$

$$c = 3e8 \text{ m/s}$$

Problems: very noisy receiver and very slow chirp speed.





40cm reflector lens

575-605 GHz beam

THz transceiver

## Operating Parameters

Standoff range:  
4-25 meters

Operating frequency:  
575-605 GHz

Range resolution  
~1 cm

Cross-range resolution:  
~1 cm

Output power:  
≤0.4 mW

Time per pixel:  
6-25 m s

# Detection of Concealed Objects on People

plastic container of BB pellets

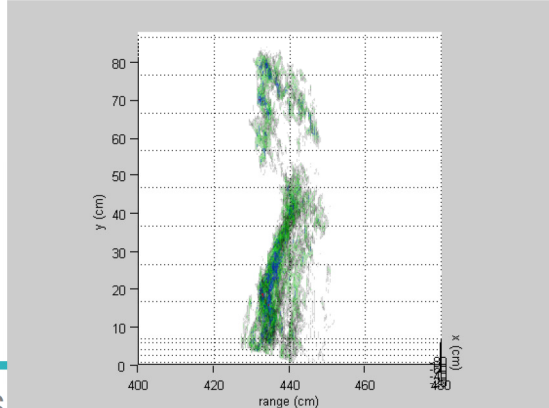
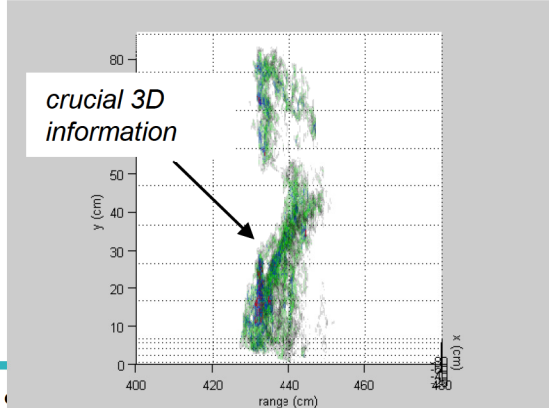
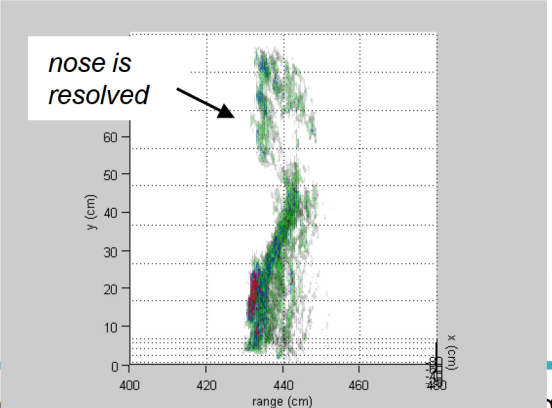
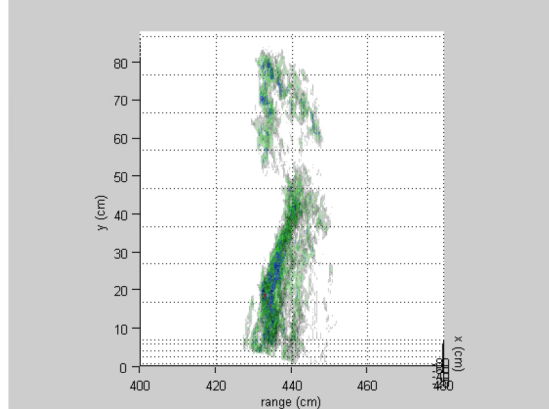
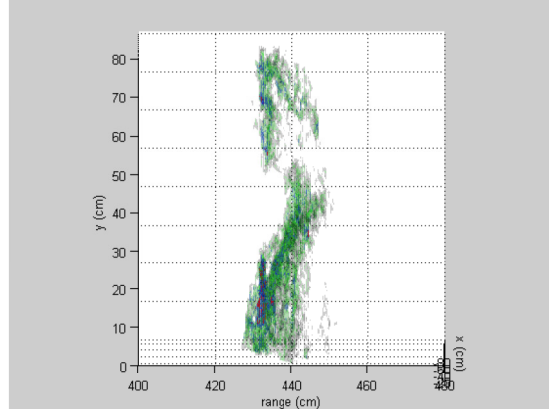
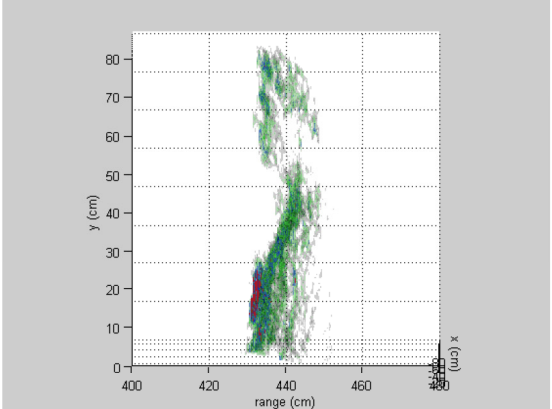
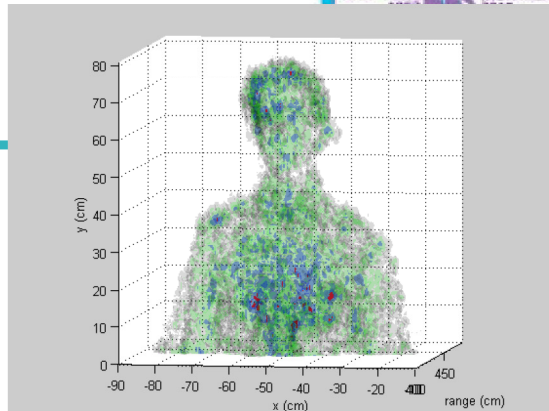
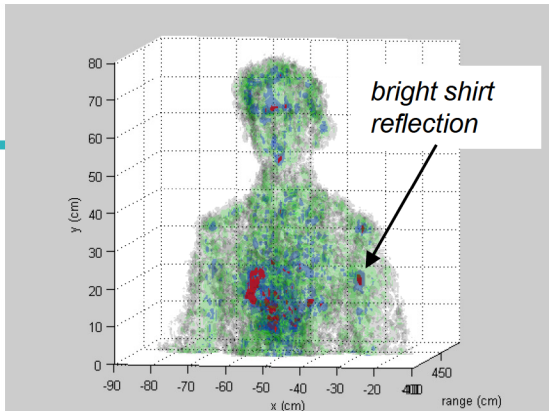
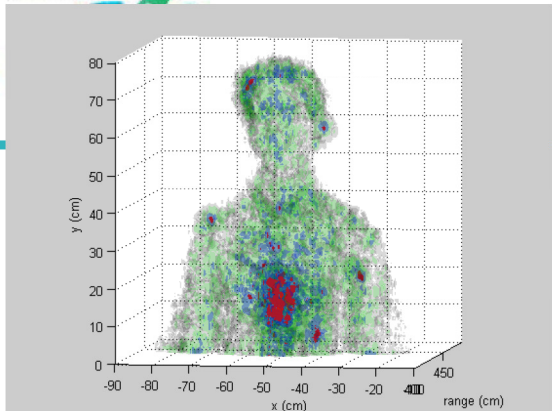


BBs concealed by shirt





8 minute scans  
100 x 110 pixels



## Recent imaging at 25 m standoff distance

	Single pixel Radar
Frequency	670 Ghz
Spot size	~ 1 cm
FoV	25x25 cm <sup>2</sup>
Range resolution	~ 1 cm
Standoff distance	Approaching 25 m
Frame rate	1 Hz

Unregister Version

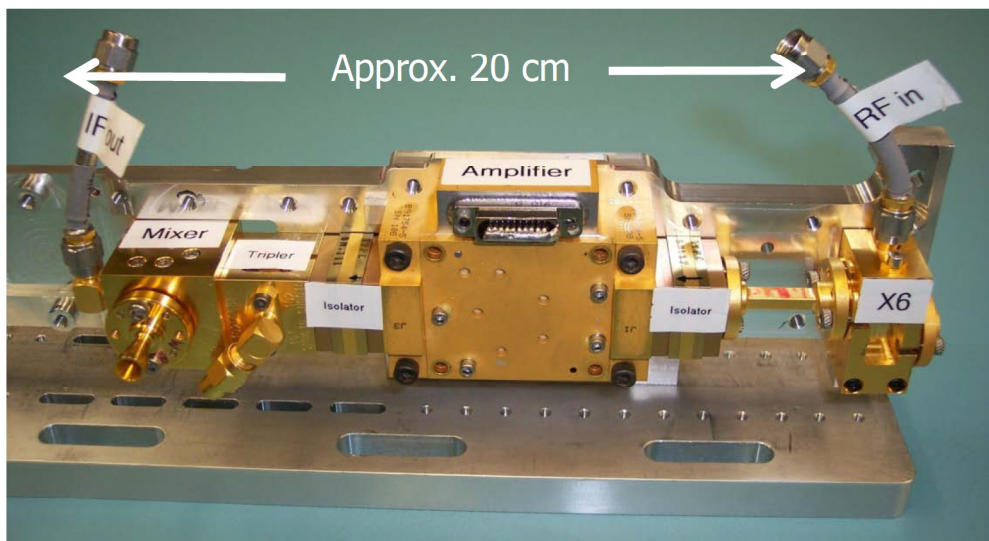


Image acquisition limited by switching mirror motor

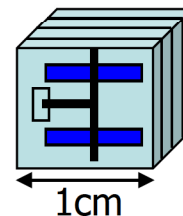


Develop an ultra-compact receiver which is compatible with array architecture

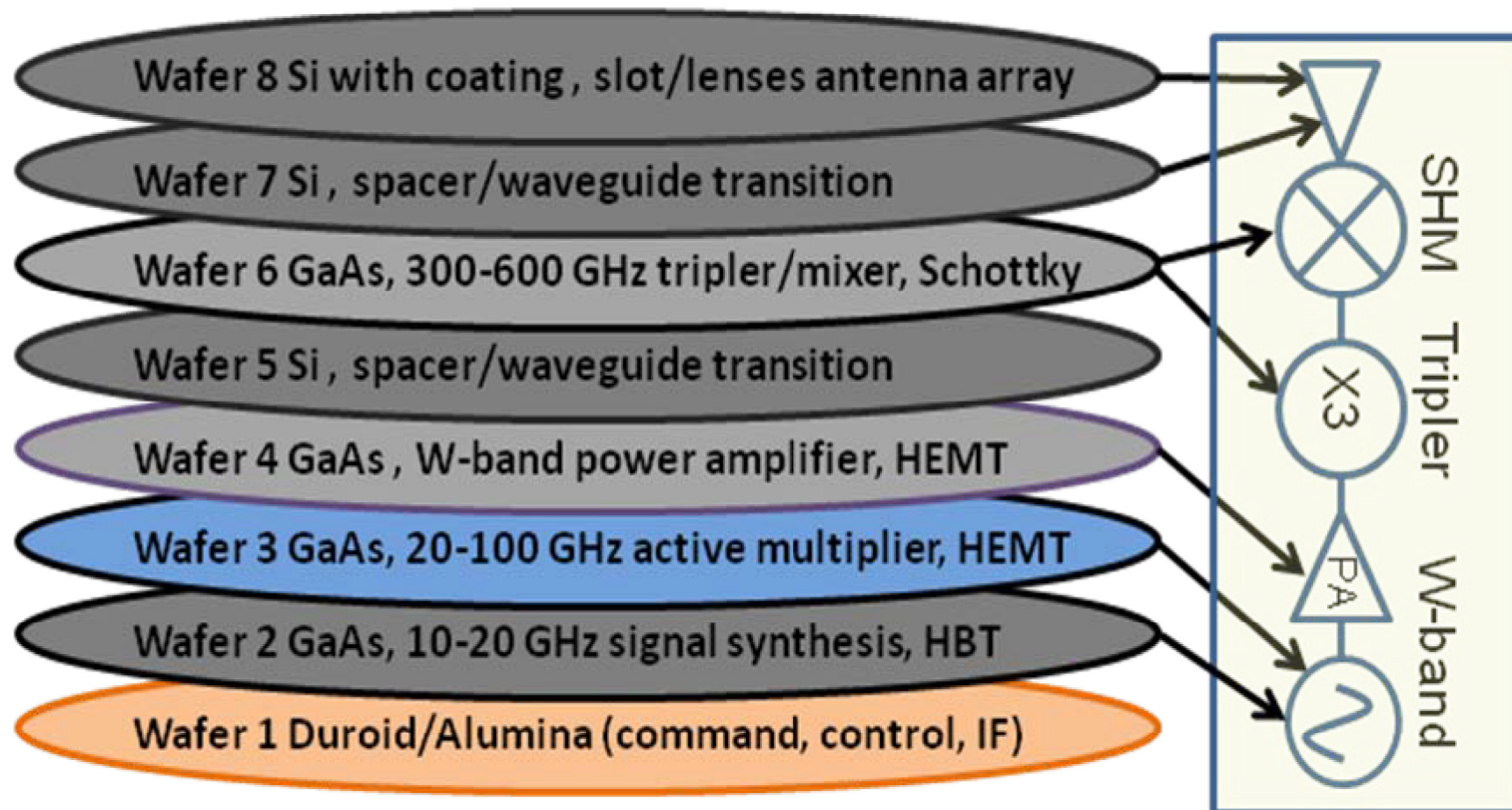
SOA 500-600 GHz Receiver Front End



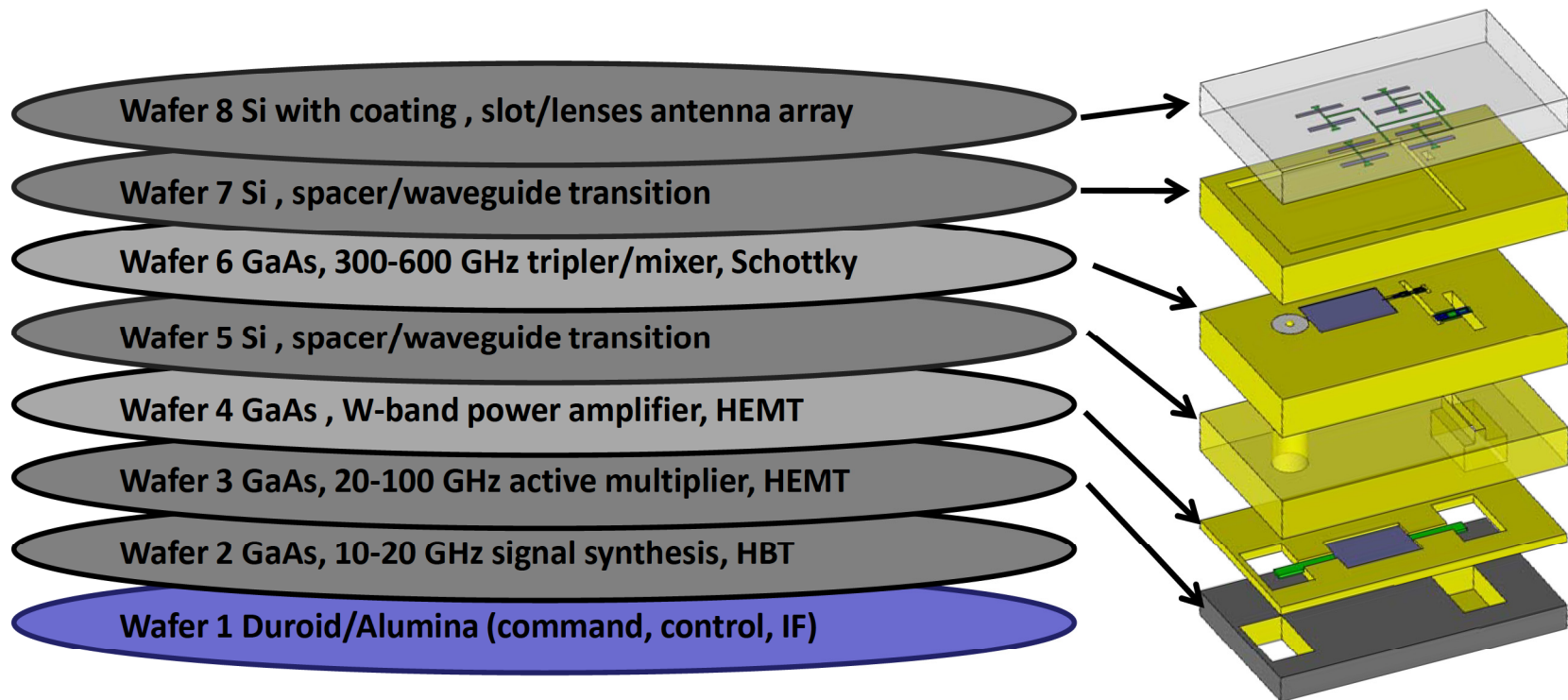
x 50 reduction in  
volume & mass



- This novel architecture uses a stack of micro-machined wafers for waveguide components and interconnections, and MMIC based GaAs wafers for amplifiers, multipliers and mixers.



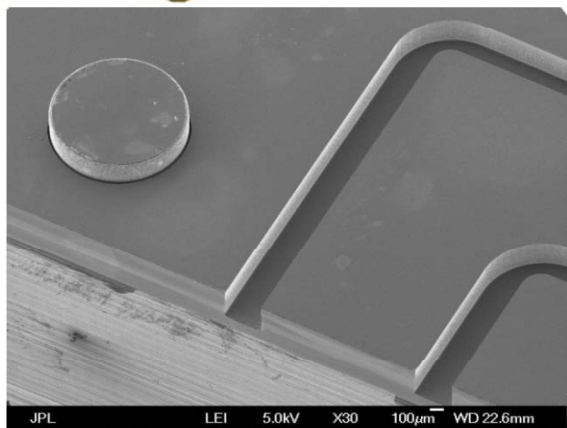
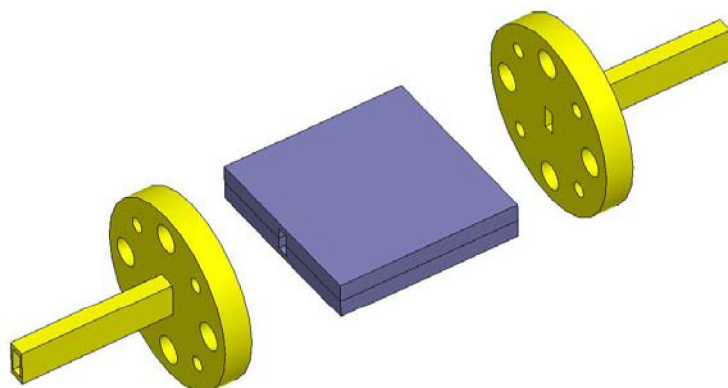
- Instead of more expensive GaAs wafers use Si wafers with discretely mounted GaAs based devices.



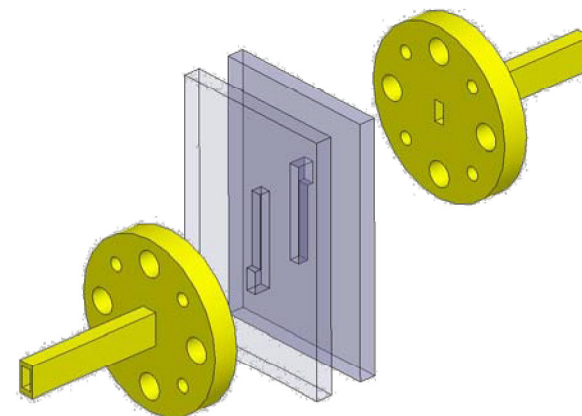


# Si-metal waveguide interconnections

- 1<sup>st</sup> option: from the side of the Si wafer



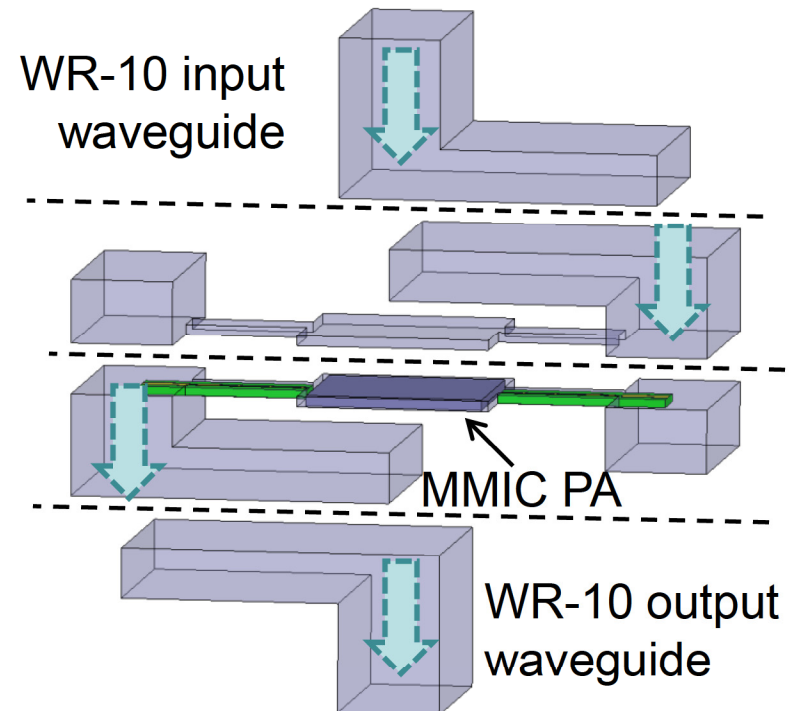
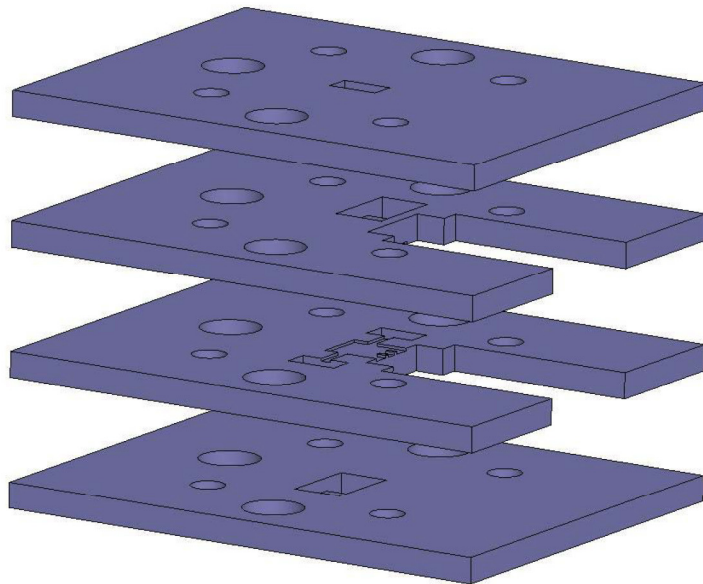
- 2<sup>nd</sup> option: from the flat of the Si wafer.



# Super compact W-band Amp

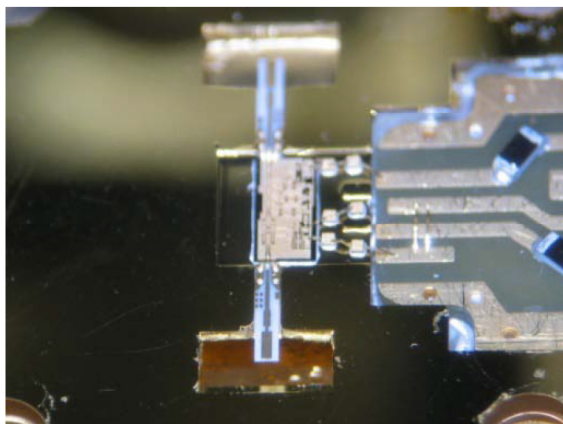


- 4 Si layers are required to package a pHEMT amplifier chip, waveguide transitions and bends.
- DC bias circuit is also included in the Si block.

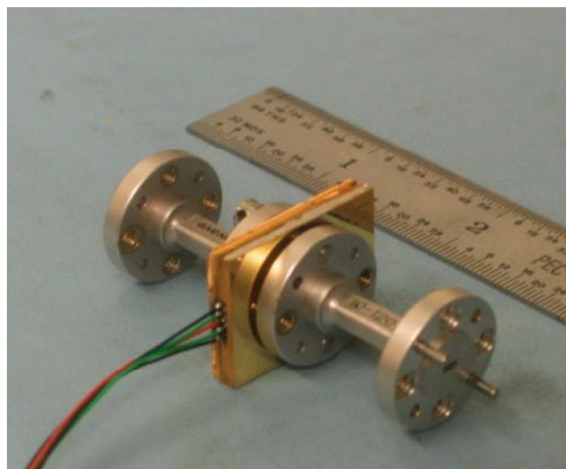
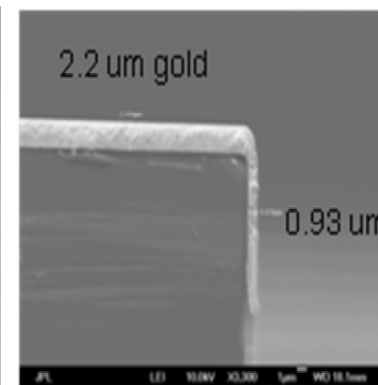
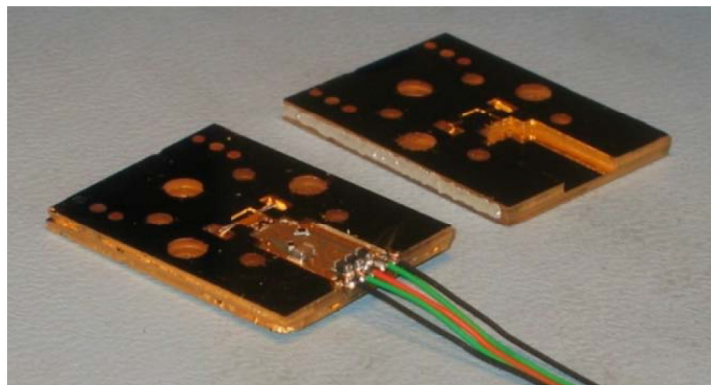


# Super compact PA module

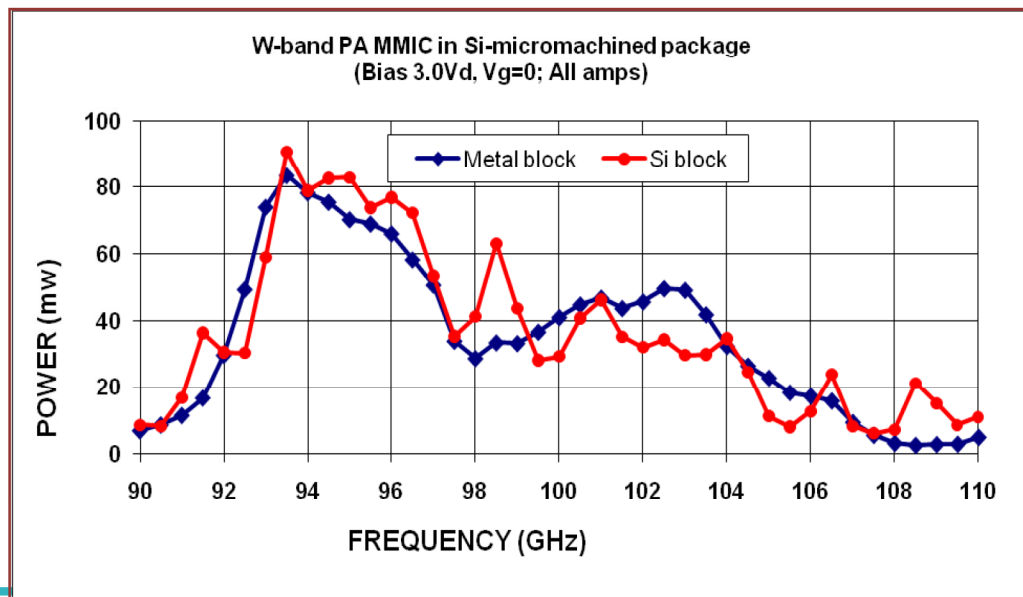
pHEMT MMIC



Deep RIE technology used to fab Si



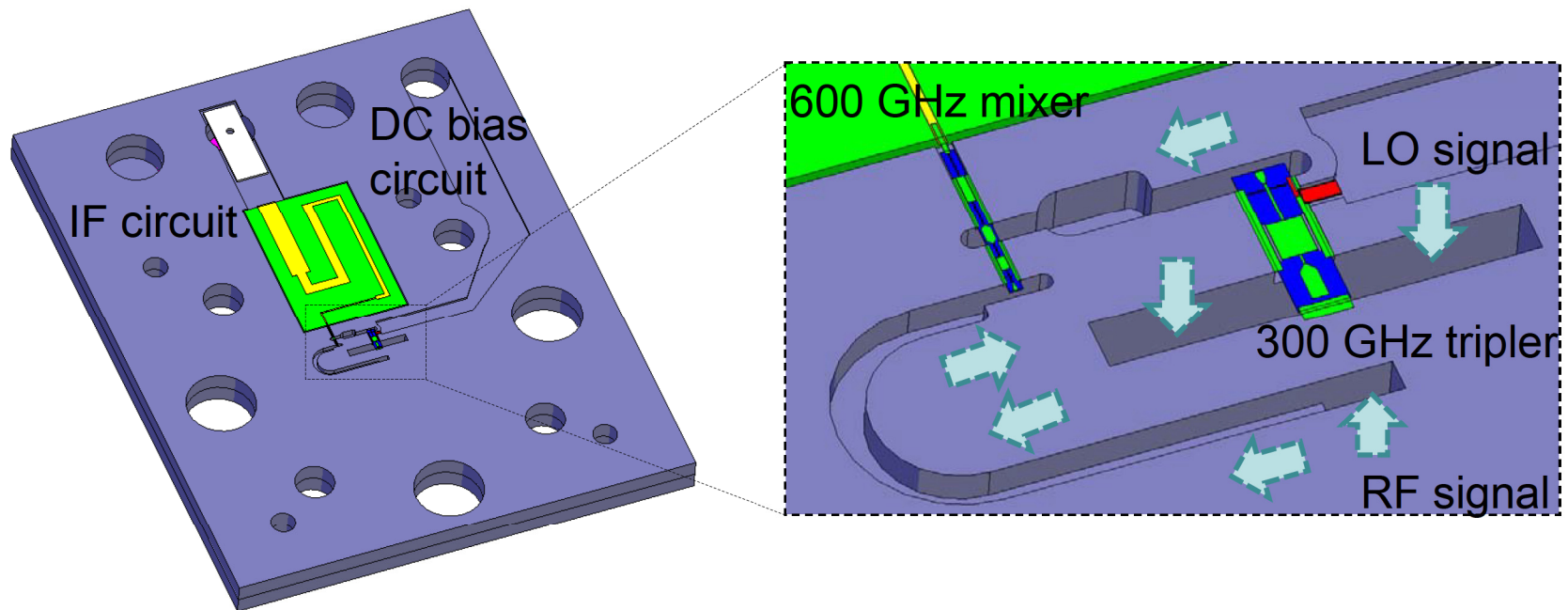
Completed module is only 7 g





# Super compact 560 GHz RFE

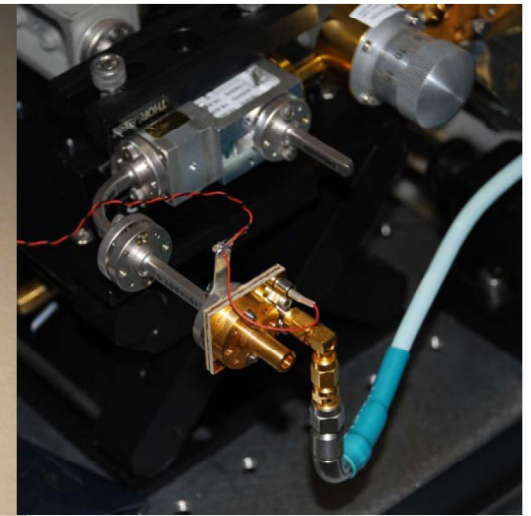
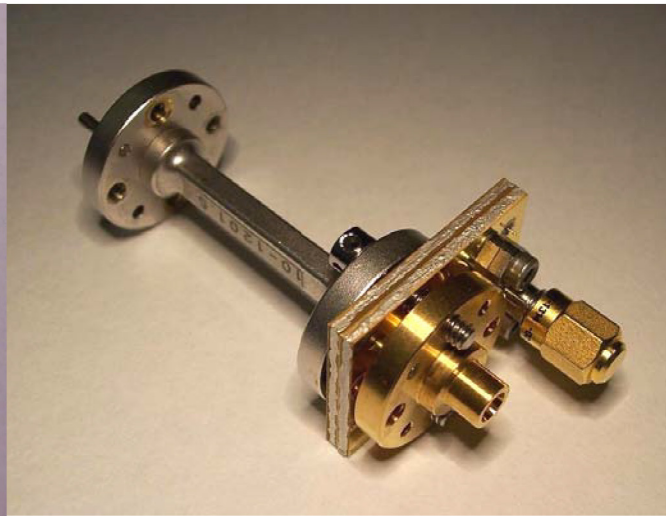
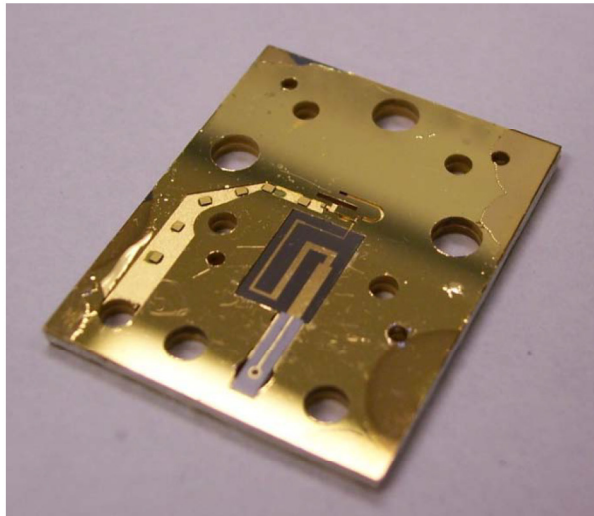
- Integrate in a Si package (4 layers) a 300 GHz MMIC tripler and 600 GHz MMIC sub-harmonic mixer



(Design courtesy of Bertrand Thomas)

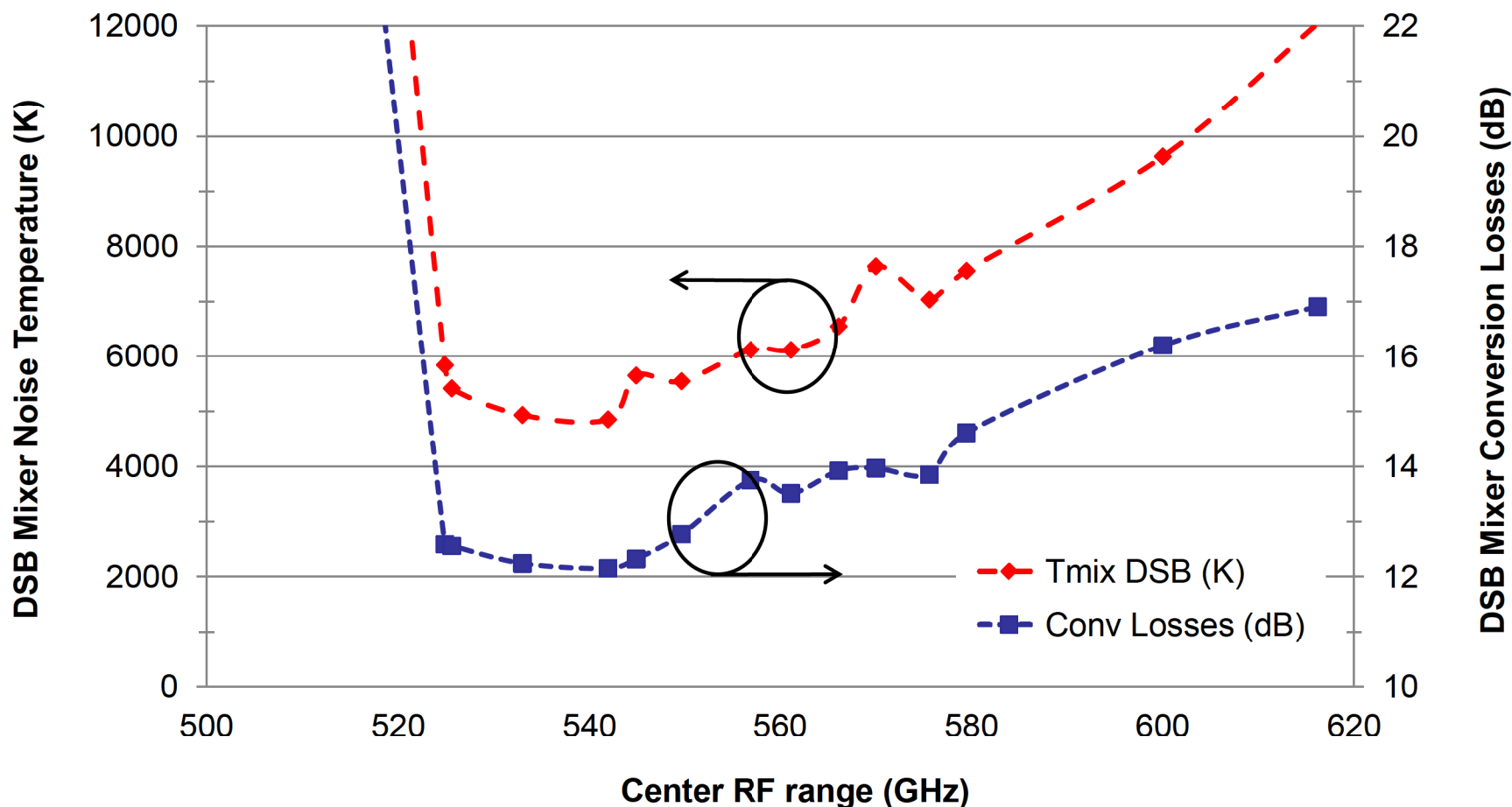
# 560 GHz RFE

- 20 x 25 x 3mm Si package
- WR-10 waveguide (input) & 560 GHz corrugated horn (output)
- SSMA and K-glass bead IF and DC connections



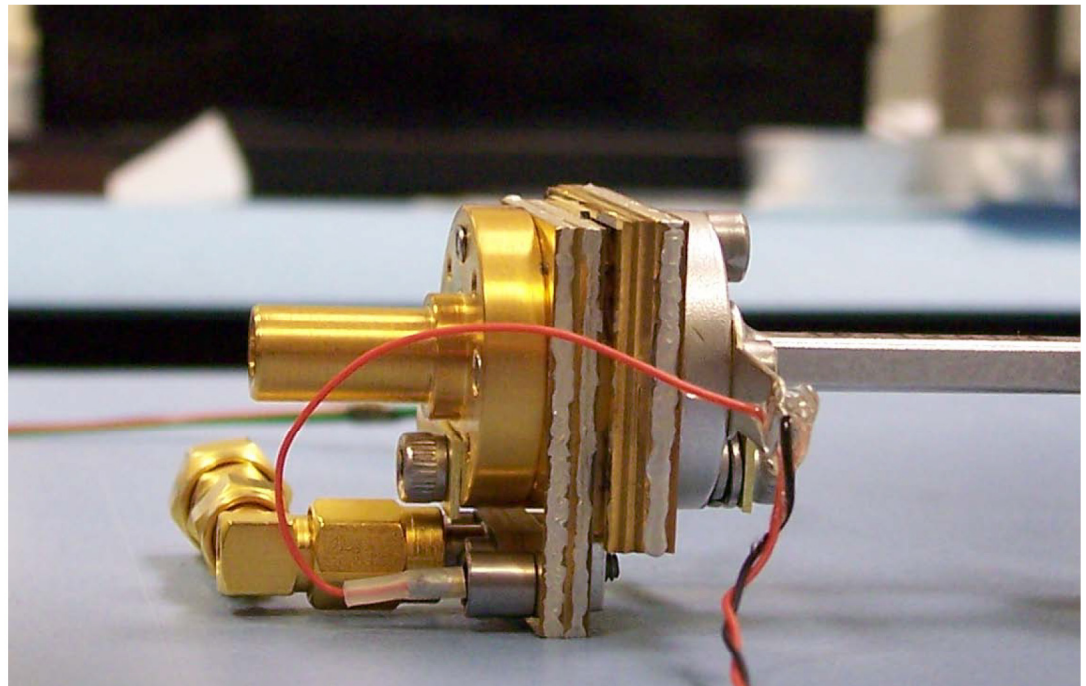
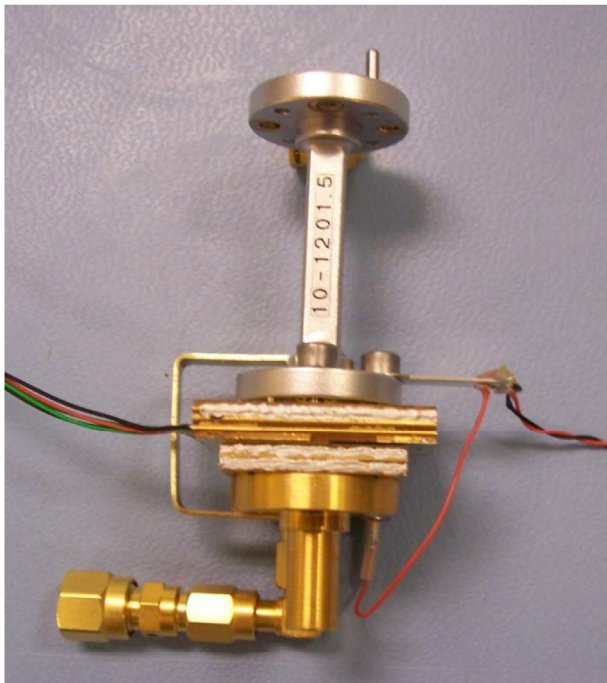
# Measured Results

- IF frequency: 4 GHz. Not corrected for IF mismatch.
- Fundamental input power at W-band : 30-50 mW



# Complete ROC front-end

- Si part is 8 mm thick.
- Size still dominated by UG387 flange.

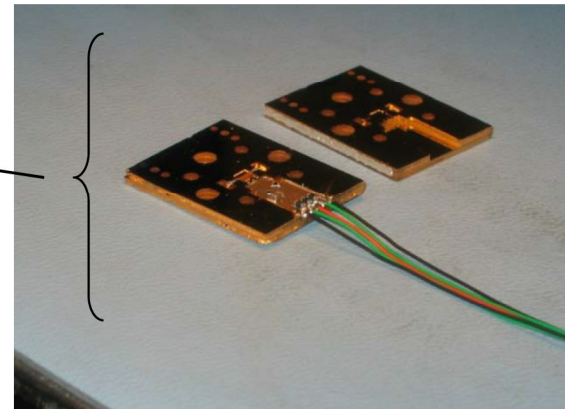
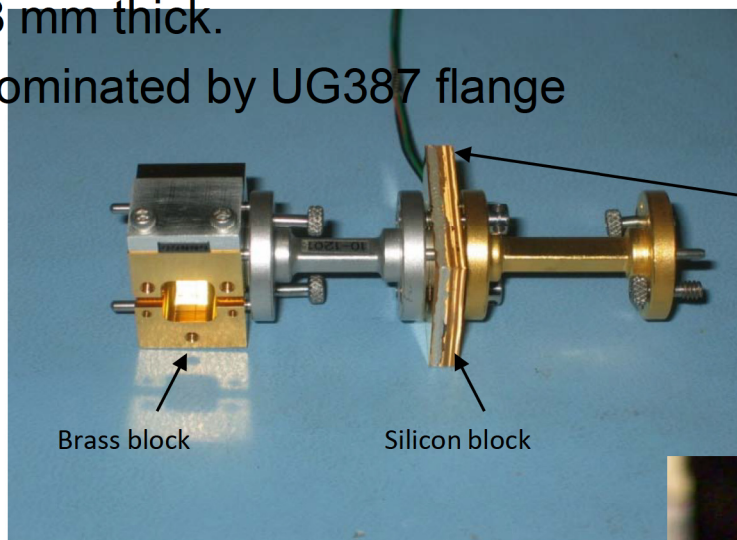




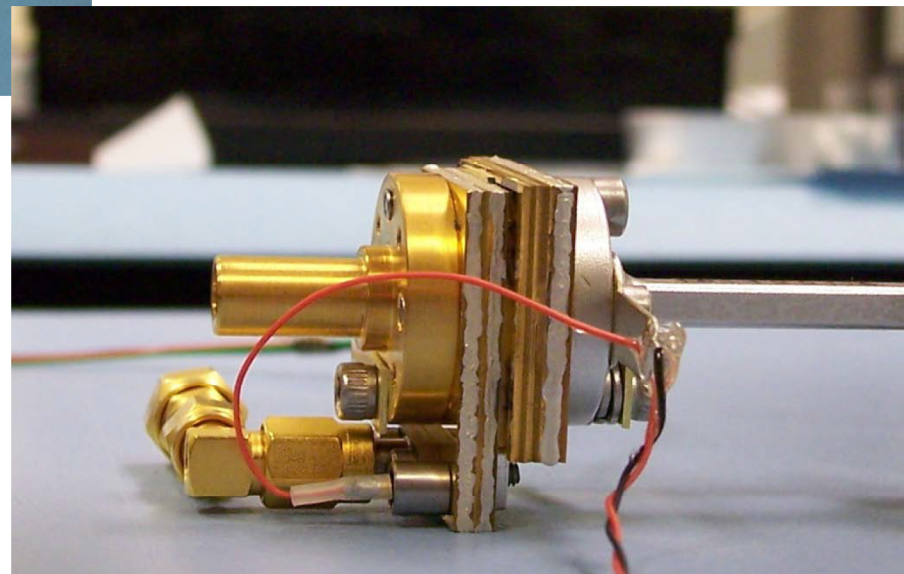
# Radiometer-on-a-chip



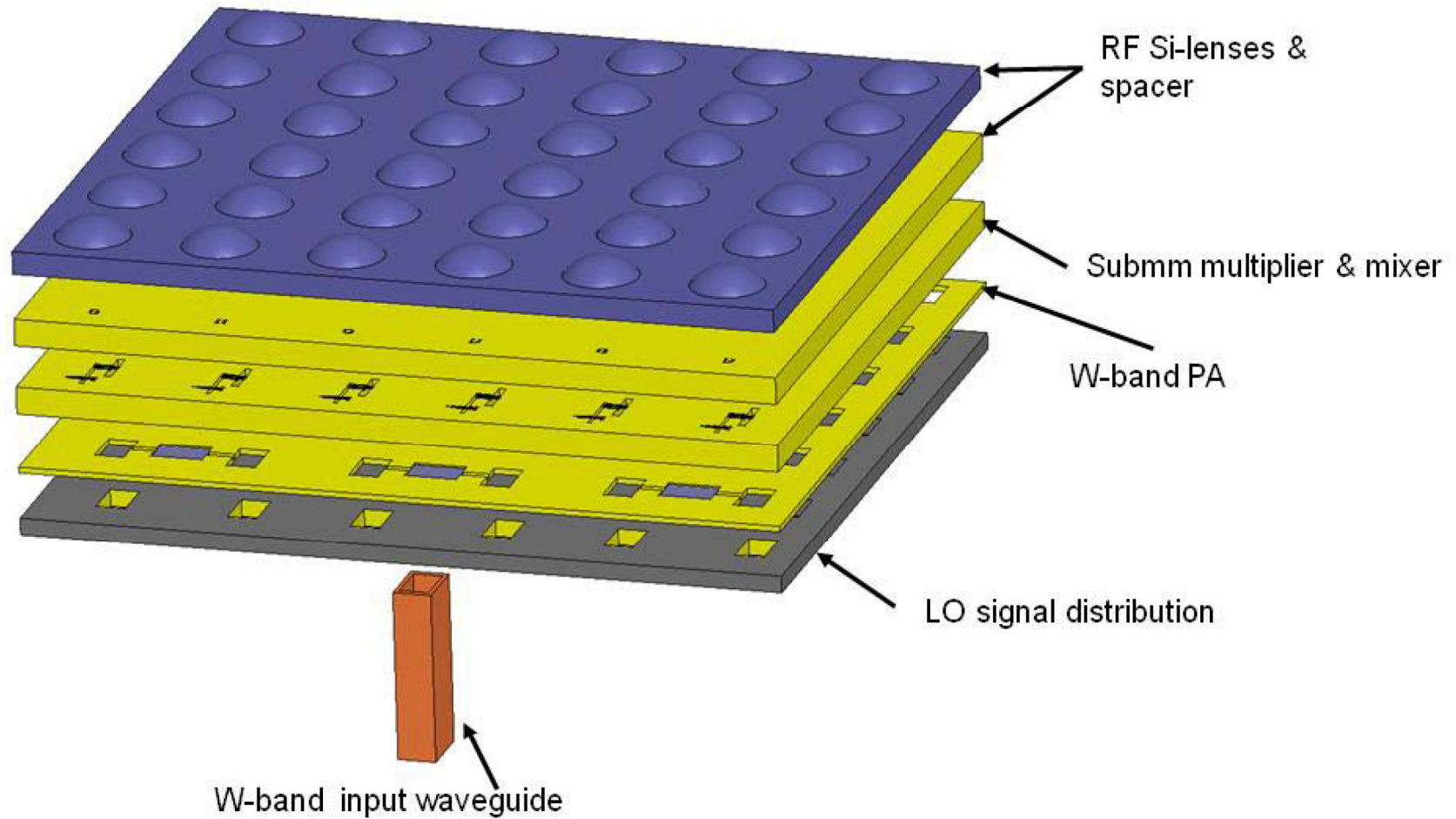
- Si part is 8 mm thick.
- Size still dominated by UG387 flange



- \* DRIE technology and wafer-bonding technology are combined to assemble silicon based waveguide blocks
- Demonstrated with w-band power amp
- Demonstrated with 600 GHz RFE
- Provides technology to achieve massive power combining



# Towards a 2D array...

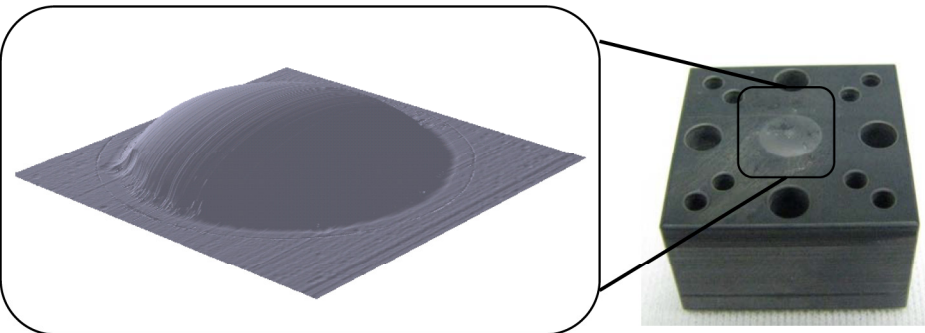




# Development of Compact Integrated Receivers: Coupling feeds

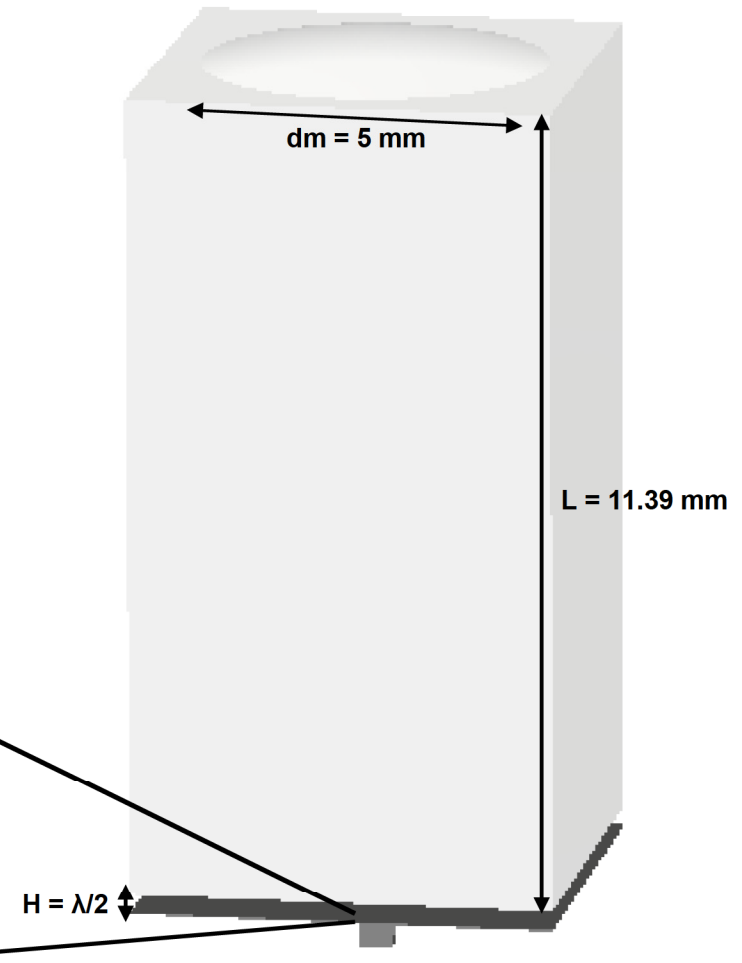
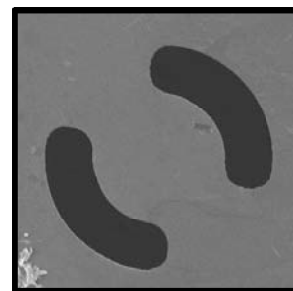
-> Silicon lens used as antenna

Proof of concept : Single pixel @ 560GHz



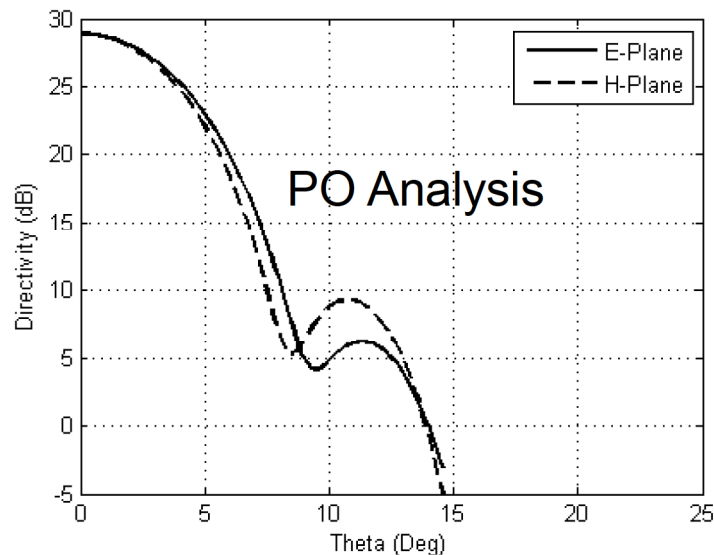
*Silicon lens fabricated with a laser machine outside of the lab*

*-> Work in progress for silicon lens micromachined with UV photolithography and DRIE techniques*

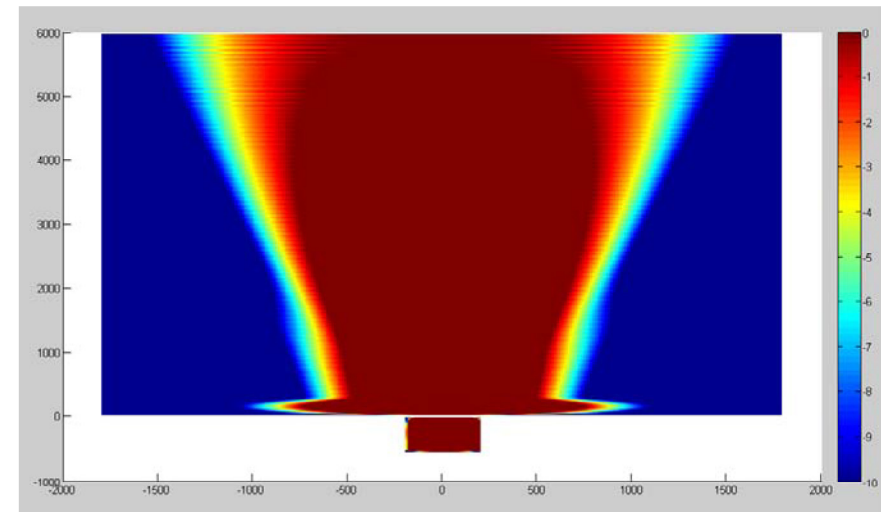
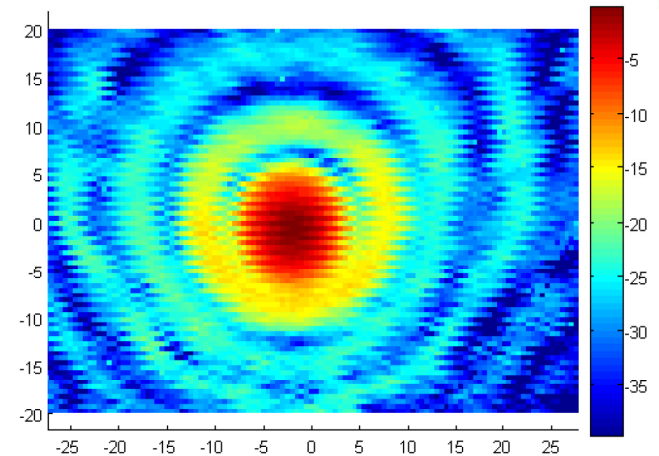


# Development of Silicon Based Integrated Receivers

Proof of concept : Single pixel @ 560GHz



$D = 28.5 \text{ dB}$   
Aperture Efficiency = 87 %



*In collaboration with Dr. Nuria Llombart and Maria Alonso from Universidad Complutense de Madrid; Spain*

# Conclusion



- THz imaging arrays continue to be challenging to implement
- Significant reduction of size and mass of current receiver front-end has been achieved with the new Si-based ROC technology
- Preliminary results are encouraging
- Development of an array is under-way